No. of Printed Pages : 2

[40/A-10]

Sardar Patel University

BSc [Semester- V] CBSC (regular) Subject Physics Course Code No: USO5CPHY05 Subject/Course Title: Analog Devices and Circuits

Thur	sday, Date 01-11-2018	Time: 10 am to 1 pm	Total Marks-70	
Q-1	Multiple Choice Questions	[Attempt all]	[10]	
(1.)	FET stands for (a) Field Effect Transformer (c) Field Energy Transfer	(b) Full Effect Transistor (d) Field Effect Transistor	I problem defre in a statipe in a station was	
(2)	A JEET has high input imp (a) It is made of semiconductor material	edance because (b) input is reversed biase	d ID	(P)
(0)	(c) of impurity atoms	(d) None of the above	Va.	s = 0 V
(3)	In a given characteristic of			
	the gate-source cutoff volt	age vgs (om)v.	1 5V	
	(a) +12 (b) -12		Vik	
	(c) +05 (d) -05	en terminate and commence and sparse	can Chap equaetti	> VDS
(4)	The typical h-parameters of	f an amplifier are $h_i = 6500$ of	$1m, h_r = 1$ and	(4) 80
` '	$h_f = -245$. Identify the con	figuration of the amplifier.		
	(a) CC	(b) CE		(a) EQ
	(c) CB	(d) Both (a) and (b)		(6) 60
(5)	If $r_{bb'}$ = 900 ohm and $r_{b'e}$ = 1	00 ohm, then hie =ohm	Draw en e swerd	
	(-) 200 - (b) 1000	(c) 90000 (d)	great in Round anger	
101	(a) 800 (b) 1000 The correct relationship is			
(6)	(a) $f_{\rm T} \approx \frac{g_{\rm m}}{2 \pi C_{\rm bc}'}$	(b) $f_T = h_{fe} f_{\beta}$		
		All -Colleges ling is on.		
	, , , , , , , , , , , , , , , , , , ,	(d) All of These		
(7)	(a) Small (b) Very small	signals compare to voltage (c) Large (d) None of	hese	
(8)	In class A operation, the o	perating point is generally loc	ated of the	lm 80
	d.c. load line.	And the second second		
	(a) At cut (b) At the (off Middle point	c) At (d) None of saturation These point		
(9)	mode OpAmp summing an (a) 500 (b) 501 (c)	-500 (d) -501	eal non-inverting	
(10)	If $A_{dm} = 2500$ and $A_{cm} = 0.2$	25, the CMRR is		
	(a) 1225 (c) 80 dB	(b) 10000 (d) Both (b) and (c)		

Q2	Answer any TEN questions in short.	[20]	
(1) (2)	Describe Gate bias. Draw a normalized transconductance curve of FET. If a JFET has V _{GS(off)}	=-6 V	
(3) (4)	and I _{DSS} = 20 mA. What is the drain current at the half cutoff point? Draw a circuit diagram of multiplexing and explain the working of it. Discuss the effect of (a) coupling capacitor and (b) emitter bypass capacitor on low frequency response.		
(5) (6)	Discuss the effect of source resistance on high frequency response. Explain importance of tuned amplifier also discuss classification of signal tuned amplifiers.	small	
(7) (8)	Explain cross over distortion. What it is caused by and how it is overcome Draw circuit diagram of transistor phase inverter. What are the limitation the circuit?	e. ons of	
(9)	Draw a labeled diagram of class AB push-pull amplifier and expla importance.	in its	
(10) (11)	Derive an expression for the voltage gain of ideal inverting Op-Amp. Calculate the output voltage of an OpAmp inverting adder for the followers of input voltages and resisters. In all cases $R_{\rm f}$ = 2000 $K\Omega$ V_1 =	-4 V.	
(12)	V_2 = 2 V, R_1 = 500 K Ω and R_2 = 1000 K Ω . What are the characteristics of an ideal operational amplifier?	the ant	
Q3 (a) Q3 (b)	/	[7] [3]	
Q3 (a) Q3 (b)	Write a note on (a) JFET Amplifier and (b) Source follower.	[7] [3]	
Q4	Draw an ac hybrid equivalent amplifier circuit and derive amplifier equations in term of the h-parameters. OR	[10]	
Q4	Define and explain FOUR h-parameters in details.	[10]	
Q5 (a) Q5 (b)		[7] [3]	÷
Q5 (a)		[7]	
Q5 (b)		[3]	
Q6 (a)	Drawing AC equivalent circuit of differential amplifier and hence derive expression for gain of the amplifier in difference mode configuration.	[7]	
Q6 (b)	Define and explain the following OpAmp parameters: (a) Input offset current (b) Input bias current and (c) Input offset voltage.	[3]	
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Q6 (a)	water and a see a second of the second of th	[7]	
Q6 (b)	Describe use of an Op-Amp as current-to-voltage converters.	[3]	